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Imaging device and electronic apparatus

Abstract

The present disclosure provides an imaging device and an electronic apparatus that can be made smaller in size, are capable of high-speed reading, and do not cause degradation of a captured image. The imaging device includes: a pixel that outputs a photoelectric conversion signal corresponding to an incident light quantity; and a comparator that compares the photoelectric conversion signal with a reference signal. The comparator includes: a differential circuit that outputs a signal corresponding to a signal difference between the photoelectric conversion signal and the reference signal; and a differential control circuit that sets an operating point of the differential circuit within a signal reset period before an operation of comparing the photoelectric conversion signal with the reference signal is started.

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Background/Summary

TECHNICAL FIELD

(1) The present disclosure relates to an imaging device and an electronic apparatus. BACKGROUND ART

(2) There is a known column-AD imaging device that performs column-by-column AD conversion on pixel signals photoelectrically converted in a plurality of pixels arranged in the column direction. In the column-AD imaging device, after a photoelectric conversion signal photoelectrically converted by a photodiode is transferred to a floating diffusion (hereinafter

- referred to as FD), the photoelectric conversion signal is normally converted into a voltage signal at a source follower circuit, and is input to an AD converter through a signal line extending in the column direction.
- (3) However, since the source follower circuit requires a long settling time, the voltage level of the signal line takes a long time to stabilize, and it is difficult to perform high-speed reading.
- (4) To perform high-speed reading, a method for reading a photoelectric conversion signal and performing AD conversion without the use of a source follower circuit has been suggested (see Patent Document 1).

CITATION LIST

Patent Document

(5) Patent Document 1: US Patent Publication US2011/0043676 A1

SUMMARY OF THE INVENTION

Problems to be Solved by the Invention

- (6) By the method according to Patent Document 1, a transistor that amplifies a photoelectric conversion signal transferred to an FD and another transistor to which a ramp wave voltage is input constitute a differential circuit, and conversion into a voltage signal is performed on the basis of a signal corresponding to a difference between the currents flowing in these transistors.
- (7) However, the transistor characteristics in the pixel and the voltage level of the FD vary with each pixel. Because of this, when a voltage signal is generated at the differential circuit described above, its voltage level fluctuates, and a captured image might be degraded.
- (8) Therefore, the present disclosure is to provide an imaging device and an electronic apparatus that can be made smaller in size to consume less power, are capable of high-speed reading, and do not cause degradation of a captured image.

(9) To solve the above problem, the present disclosure provides an imaging device that includes: a

Solutions to Problems

- pixel that outputs a photoelectric conversion signal corresponding to an incident light quantity; and a comparator that compares the photoelectric conversion signal with a reference signal, the comparator including: a differential circuit that outputs a signal corresponding to a signal difference between the photoelectric conversion signal and the reference signal; and a differential control circuit that sets an operating point of the differential circuit within a signal reset period before an operation of comparing the photoelectric conversion signal with the reference signal is started. (10) The comparator may include a first current source connected to the differential circuit, the pixel may include a first transistor that generates a current corresponding to the photoelectric conversion signal, the differential circuit may include a second transistor that generates a current corresponding to the reference signal, the differential circuit may output a signal corresponding to a difference between the current flowing in the first transistor and the current flowing in the second transistor, and the first current source may generate and apply a current obtained by adding the
- (11) The differential circuit may include a third transistor that is cascode-connected to the first transistor, and is turned on when the pixel to be read is read, and the first current source may generate and apply a current obtained by adding the current flowing in the first transistor and the third transistor, and the current flowing in the second transistor.

current flowing in the first transistor and the current flowing in the second transistor.

- (12) The differential control circuit may include a second current source and a third current source that are connected in series between a first reference voltage node and a second reference voltage node, the second current source may include a fourth transistor and a fifth transistor that are cascode-connected between the first reference voltage node and an input node of the third current source, and a connection node between the fourth transistor and the fifth transistor may be connected to the second transistor.
- (13) The differential control circuit may include an output node that outputs the signal corresponding to the signal difference, from a connection node between the second current source

- and the third current source, and the differential control circuit may perform negative feedback control on the voltage level of the output node within the signal reset period.
- (14) The comparator may include a sixth transistor that switches whether or not to short-circuit the gate of the second transistor and the output node, and the sixth transistor may be turned on within the signal reset period, to short-circuit the gate of the second transistor and the output node.
- (15) A capacitor that is connected between the gate of the second transistor and an input node of the reference signal may be further provided, and the input node of the reference signal may be set at a predetermined voltage level while the sixth transistor is on.
- (16) The gate voltages of the fourth transistor and the fifth transistor may be adjusted, to set the voltage level of the output node at a predetermined voltage level within the signal reset period.
- (17) The voltage levels of the gate voltages of the fourth transistor and the fifth transistor may be maintained after the operating point is set.
- (18) The gate voltages of the fourth transistor and the fifth transistor may be set at a voltage level at which the fourth transistor and the fifth transistor operate in a saturated state.
- (19) Each of the fourth transistor and the fifth transistor may be a P-type MOS transistor, and the gate of the fifth transistor may be set at a lower voltage level than the voltage level of the gate of the fourth transistor.
- (20) A seventh transistor and an eighth transistor that are cascode-connected between the first reference voltage node and the second reference voltage node may be further provided, a predetermined bias signal may be supplied to the gate of the seventh transistor, and the output node may be connected to the gate of the eighth transistor.
- (21) A ninth transistor that is connected in parallel to the fourth transistor, and is cascode-connected to the second transistor may be further provided.
- (22) When the gate voltage of the first transistor drops, the gate voltage of the ninth transistor may be adjusted, to apply the same current as the current flowing before the drop in the gate voltage of the first transistor to the first current source.
- (23) A tenth transistor that is connected in parallel to the second transistor may be further provided, and the output node may be connected to the gate of the tenth transistor.
- (24) The differential circuit may compare the sum of the currents flowing in a plurality of the first transistors provided in a plurality of the pixels with the current flowing in the second transistor, and output the signal corresponding to the signal difference.
- (25) A selector that selects at least one first transistor of a plurality of the first transistors provided in a plurality of the pixels may be further provided, and the differential circuit may compare the sum of the currents flowing in the at least one first transistor selected by the selector with the current flowing in the second transistor, and output the signal according to the signal difference.
- (26) The imaging device may further include: a first substrate in which a plurality of the pixels is disposed; and a second substrate that is stacked on the first substrate, the comparator being disposed in the second substrate.
- (27) An imaging device may include: a pixel including a photoelectric conversion element and an amplification transistor; a differential circuit that is formed with the amplification transistor, a first transistor that receives a reference signal, and a first current source; a second current source and a third current source that are connected in series between a first reference voltage node and a second reference voltage node; and a second transistor disposed between the second current source and the third current source, in which a node between the second current source and the second transistor may be connected to the first transistor.
- (28) The present disclosure provides an electronic apparatus that includes: a solid-state imaging device that outputs an imaging pixel signal subjected to photoelectric conversion in a plurality of pixels; and a signal processing device that performs signal processing on the basis of the imaging pixel signal, in which the solid-state imaging device includes a comparator that compares a photoelectric conversion signal with a reference signal, and the comparator includes: a differential

circuit that outputs a signal corresponding to a signal difference between the photoelectric conversion signal and the reference signal; and a differential control circuit that sets an operating point of the differential circuit within a signal reset period before an operation of comparing the photoelectric conversion signal with the reference signal is started.

Description

BRIEF DESCRIPTION OF DRAWINGS

- (1) FIG. **1** is a block diagram showing an embodiment of an imaging device to which the present technology is applied.
- (2) FIG. **2** is a circuit diagram showing an example internal configuration of a pixel provided in a pixel unit.
- (3) FIG. **3** is a circuit diagram showing an example internal configuration of each comparator shown in FIG. **1**.
- (4) FIG. **4** is a circuit diagram of a comparator that further includes an initialization circuit for initializing the voltage level of the output node n**1** shown in FIG. **3**.
- (5) FIG. **5** is an operation timing diagram of the comparator shown in FIG. **3**.
- (6) FIG. **6** is a circuit diagram of a comparator according to a comparative example.
- (7) FIG. **7** is a circuit diagram of a first modification of the comparator shown in FIG. **3**.
- (8) FIG. **8** is a circuit diagram of a second modification of the comparator shown in FIG. **3**.
- (9) FIG. **9** is a circuit diagram of a third modification of the comparator shown in FIG. **3**.
- (10) FIG. **10** is a circuit diagram of a fourth modification of the comparator shown in FIG. **3**.
- (11) FIG. **11** is a circuit diagram of an imaging device including the comparator shown in FIG. **9**.
- (12) FIG. **12**A is a layout diagram of a first substrate.
- (13) FIG. **12**B is a layout diagram of a second substrate.
- (14) FIG. **13** is a block diagram showing an example of a schematic configuration of a vehicle control system that is an example of a mobile structure control system.
- (15) FIG. **14** is a diagram showing an example of the installation positions of imaging sections. MODES FOR CARRYING OUT THE INVENTION
- (16) The following is a description of embodiments of an imaging device and an electronic apparatus, with reference to the drawings. Although principal components of the imaging device and the electronic apparatus will be mainly described below, the imaging device and the electronic apparatus may include components and functions that are not illustrated or described. The following description does not exclude components and functions that are not illustrated or described.
- (17) < Example Configuration of an Imaging Device>
- (18) FIG. **1** is a block diagram showing an embodiment of an imaging device **100** to which the present technology is applied.
- (19) The imaging device **100** includes a pixel unit **101**, a timing control circuit **102**, a vertical scanning circuit **103**, a digital-analog converter (DAC) **104**, an analog-digital converter (ADC) group **105**, a horizontal transfer scanning circuit **106**, an amplifier circuit **107**, and a signal processing circuit **108**.
- (20) Unit pixels (hereinafter also simply referred to as pixels) each including a photoelectric conversion element that photoelectrically converts incident light into a charge amount corresponding to the light quantity thereof are arranged in a matrix in the pixel unit **101**. A specific circuit configuration of the unit pixels will be described later with reference to FIG. **2**. Also, in the pixel unit **101**, for the pixel array in the matrix, a pixel drive line **109** is disposed in the transverse direction in the drawing (the pixel array direction of the pixel row/a horizontal direction) for each row, and a vertical signal line **110** is disposed in the vertical direction of the drawing (the pixel

array direction of the pixel column/a perpendicular direction) for each column. One end of each pixel drive line **109** is connected to the output terminal corresponding to each corresponding row of the vertical scanning circuit **103**. Note that, in FIG. **1**, one pixel drive line **109** is shown for each pixel row. However, two or more pixel drive lines **109** may be provided for each pixel row.

- (21) The timing control circuit **102** includes a timing generator (not shown) that generates various kinds of timing signals. The timing control circuit **102** performs drive control on the vertical scanning circuit **103**, the DAC **104104**, the ADC group **105**, the horizontal transfer scanning circuit **106**, and the like, on the basis of various timing signals generated by the timing generator on the basis of a control signal or the like provided from the outside.
- (22) The vertical scanning circuit **103** is formed with a shift register, an address decoder, and the like. Although a specific configuration is not shown in this drawing, the vertical scanning circuit **103** includes a reading scanning system and a sweeping scanning system.
- (23) The reading scanning system sequentially performs selective scanning row by row for unit pixels from which signals are to be read. Meanwhile, the sweeping scanning system performs, on the read rows on which reading scanning is to be performed by the reading scanning system, sweeping scanning to sweep (reset) unnecessary charges from the photoelectric conversion elements of the unit pixels in the read rows prior to the reading scanning by the time corresponding to the shutter speed. A so-called electronic shutter operation is performed by the sweeping scanning system sweeping (resetting) the unnecessary charges. Here, the electronic shutter operation means an operation of discarding the optical charges of the photoelectric conversion elements and newly starting exposure (starting accumulating optical charges). The signals read in the reading operation performed by the reading scanning system corresponds to the amount of light that has entered after the immediately preceding reading operation or the electronic shutter operation. Further, the period from the reading timing in the immediately preceding reading operation or the sweeping timing in the electronic shutter operation to the reading timing in the current reading operation is the optical charge accumulation duration (exposure duration) in the unit pixel.
- (24) A pixel signal VSL that is output from each unit pixel of the pixel row selectively scanned by the vertical scanning circuit **103** is supplied to the ADC group **105** via the vertical signal line **110** of each column.
- (25) The DAC **104** generates a reference signal RAMP that is a signal of a linearly increasing ramp waveform, and supplies the reference signal RAMP to the ADC group **105**.
- (26) The ADC group **105** includes comparators **121-1** to **121**-*n*, counters **122-1** to **122**-*n*, and latches **123-1** to **123**-*n*. Note that, hereinafter, in a case where there is no need to distinguish the comparators **121-1** to **121**-*n* from one another, the counters **122-1** to **122**-*n* from one another, and the latches **123-1** to **123**-*n* from one another, they will be referred to simply as the comparators **121**, the counters **122**, and the latches **123**.
- (27) One comparator **121**, one counter **122**, and one latch **123** are provided for each column in the pixel unit **101**, to constitute an ADC. That is, the ADC group **105** is provided with an ADC for each column in the pixel unit **101**.
- (28) Each comparator **121** compares the pixel signal VSL output from each corresponding pixel with the reference signal RAMP, and supplies an output signal indicating a comparison result to the corresponding counter **122**.
- (29) The counter **122** counts the duration until the signal obtained by adding the pixel signal VSL and the reference signal RAMP via a capacitance exceeds a predetermined reference voltage on the basis of the output signal of the comparator **121**, to convert the analog pixel signal into a digital pixel signal represented by a count value. The counter **122** supplies the count value to the latch **123**.
- (30) The latch **123** holds the count value supplied from the counter **122**. The latch **123** also performs correlated double sampling (CDS) by calculating a difference between the count value of the D-phase corresponding to the pixel signal at a signal level and the count value of the P-phase

corresponding to the pixel signal at a reset level.

- (31) The horizontal transfer scanning circuit **106** is formed with a shift register, an address decoder, and the like, and sequentially and selectively scans circuit portions corresponding to the pixel columns in the ADC group **105**. As the horizontal transfer scanning circuit **106** performs the selective scanning, the digital pixel signals held in the latches **123** are sequentially transferred to the amplifier circuit **107** via a horizontal transfer line **111**.
- (32) The amplifier circuit **107** amplifies the digital pixel signals supplied from the latches **123**, and supplies the amplified digital pixel signals to the signal processing circuit **108**.
- (33) The signal processing circuit **108** performs predetermined signal processing on the digital pixel signals supplied from the amplifier circuit **107**, to generate two-dimensional image data. For example, the signal processing circuit **108** corrects a vertical line defect or a point defect, clamps signals, or performs digital signal processing such as parallel-serial conversion, compression, encoding, adding, averaging, and intermittent operation. The signal processing circuit **108** outputs the generated image data to a device in the subsequent stage.
- (34) <Example Configuration of a Pixel>
- (35) FIG. **2** is a circuit diagram showing an example internal configuration of a pixel **150** provided in the pixel unit **101**.
- (36) The pixel **150** includes a photoelectric conversion element and a readout circuit. The photoelectric conversion element includes a photodiode **151**, for example. The readout circuit includes a transfer transistor **152**, an amplification transistor **154**, a select transistor **155**, and a reset transistor **156**, for example. FIG. **2** shows an example in which these transistors are formed with N-type MOS transistors.
- (37) The photodiode **151** photoelectrically converts incident light into charges (electrons in this case) of the amount corresponding to the quantity of the incident light.
- (38) The transfer transistor **152** is connected between the photodiode **151** and a floating diffusion (FD) **153**. When turned on by a drive signal TX supplied from the vertical scanning circuit **103**, the transfer transistor **152** transfers the charge accumulated in the photodiode **151** to the FD **153**.
- (39) A gate of the amplification transistor **154** is connected to the FD **153**. The amplification transistor **154** is connected to the vertical signal line **110** via the select transistor **155**, and constitutes, together with a current source **157** outside the pixel unit **101**, a source follower circuit. When the select transistor **155** is turned on by a drive signal SEL supplied from the vertical scanning circuit **103**, the amplification transistor **154** amplifies the potential of the FD **153**, and outputs a pixel signal indicating the voltage corresponding to the potential, to the vertical signal line **110**. The pixel signal output from each pixel **150** is then supplied to each corresponding comparator **121** of the ADC group **105** via the vertical signal line **110**.
- (40) In this embodiment, as the amplification transistor **154** and the select transistor **155** are used as part of the comparator **121** as described later, the current source **157** and the source follower circuit are made unnecessary.
- (41) The reset transistor **156** is connected between a power supply VDD and the FD **153**. When the reset transistor **156** is turned on by a drive signal RST supplied from the vertical scanning circuit **103**, the potential of the FD **153** is reset to the potential of the power supply VDD.
- (42) <Example Configuration of a Comparator>
- (43) FIG. **3** is a circuit diagram showing an example internal configuration of each comparator **121** shown in FIG. **1**. The comparator **121** in FIG. **3** includes a differential circuit **11** and a differential control circuit **12**.
- (44) The differential circuit **11** outputs a signal corresponding to a signal difference between a photoelectric conversion signal and a reference signal. The photoelectric conversion signal is a signal obtained by the amplification transistor **154** amplifying the potential of the FD **153**. The circuit configuration of differential circuit **11** will be described later in detail.
- (45) The differential control circuit 12 sets an operating point of the differential circuit 11 within a

- signal reset period before an operation of comparing the photoelectric conversion signal with the reference signal is started.
- (46) The differential circuit **11** outputs a signal corresponding to a difference between the currents flowing in a first transistor **Q1** and a second transistor **Q2** that constitute a differential pair. The first transistor **Q1** is the amplification transistor **154** in the pixel **150**. In the normal pixel **150**, as shown in FIG. **2**, the select transistor (a third transistor **Q3**) **155** is cascode-connected to the amplification transistor **154**. Accordingly, the differential circuit **11** outputs a signal corresponding to a difference between the current flowing in the first transistor **Q1** and the third transistor **Q3**, and the current flowing in the second transistor **Q2**. The reference signal is supplied to the gate of the second transistor **Q2** via a capacitor **C1**.
- (47) As described above, the differential circuit **11** according to this embodiment compares the current flowing in the amplification transistor **154** and the select transistor **155** in the pixel **150**, directly with the current flowing in the second transistor **Q2** to which the reference signal is supplied at the gate. As a result, the dynamic range can be made wider, and reading can be performed at higher speed than in a case where the current flowing in the first transistor **Q1** is converted into a voltage signal by the source follower circuit and is then compared with the reference signal. This effect will be described later in detail.
- (48) The comparator **121** in FIG. **3** includes a first current source **13** connected to the differential circuit **11**. A current obtained by adding the current flowing in the first transistor Q**1** and the current flowing in the second transistor Q**2** flows in the first current source **13**. The first current source **13** includes an N-type MOS transistor, for example. A bias signal BIAS_N**1** is supplied to the gate of this transistor. The voltage of the bias signal BIAS_N**1** is controlled, so that the total amount of current flowing in the first transistor Q**1** and the second transistor Q**2** in the differential circuit **11** can be adjusted.
- (49) The differential control circuit **12** includes a second current source **14** and a third current source **15** connected in series between a power-supply voltage node (a first reference voltage node) VDDH and a ground node (a second reference voltage node). The second current source **14** includes a fourth transistor **Q4** and a fifth transistor **Q5** cascode-connected between the power-supply voltage node VDDH and an output node n**1** of the comparator **121**. The fourth transistor **Q4** and the fifth transistor **Q5** are P-type MOS transistors, for example. A bias signal BIAS_P**1** is supplied to the gate of the fourth transistor **Q4**, and a bias signal BIAS_P**2** is supplied to the gate of the fifth transistor **Q5**.
- (50) The connection node between the fourth transistor Q4 and the fifth transistor Q5 is connected to the drain of the second transistor Q2. The current flowing in the second current source 14 is determined with the characteristics of the pixel 150, variations of the respective transistors in the pixel 150, and the like being taken into consideration. In this embodiment, at a time of signal resetting, the signal voltage of the output node n1 of the comparator 121 is subjected to negative feedback control, and the bias signals BIAS_P1 and BIAS_P2 of the fourth transistor Q4 and the fifth transistor Q5 are adjusted so that the output node n1 of the comparator 121 is set at a desired voltage level.
- (51) Further, the bias signals BIAS_P1 and BIAS_P2 are set at voltage levels at which the fourth transistor Q4 and the fifth transistor Q5 operate in a saturated state. The method for setting the bias signals BIAS_P1 and BIAS_P2 will be described later.
- (52) In FIG. **3**, the connection node n**1** between the second current source **14** and the third current source **15** is the output node n**1** of the comparator **121**, but a circuit for increasing the gain may be connected to the connection node n**1** between the second current source **14** and the third current source **15**, and the connection node n**1** may not be the output node n**1** of the comparator **121** in some cases. Note that, in this specification, the connection node between the second current source **14** and the third current is sometimes referred to as the output node n**1** of the comparator **121**. (53) The third current source **15** includes an N-type MOS transistor, for example. This transistor is

connected between the output node n**1** of the comparator **121** and the ground node. A bias signal BIAS_N**2** is supplied to the gate of this transistor.

- (54) The comparator **121** includes a sixth transistor Q**6** that switches whether or not to short-circuit the gate of the second transistor Q**2** and the output node n**1** of the comparator **121**. The sixth transistor Q**6** is a P-type MOS transistor, for example. An AZP signal is supplied to the gate of the sixth transistor Q**6**. The AZP signal temporarily switches to a low potential at the time of signal resetting. When the AZP signal switches to the low potential, the sixth transistor Q**6** is turned on, and the gate of the second transistor Q**2** and the output node n**1** of the comparator **121** are short-circuited. When the sixth transistor Q**6** is turned on, the operation of setting the operating point of the differential circuit **11** is performed.
- (55) The comparator **121** according to this embodiment performs an operation (a P-phase operation) of comparing the signal with the reference signal at the time of signal resetting that does not involve photoelectric conversion, and then performs an operation (a D-phase operation) of comparing the photoelectric conversion signal with the reference signal.
- (56) FIG. **4** is a circuit diagram of a comparator **121** that further includes an initialization circuit **20** for initializing the voltage level of the output node n**1** in FIG. **3**. The initialization circuit **20** in FIG. **4** includes an N-type MOS transistor, for example, and an initialization signal PAC is supplied to the gate of this transistor. When the initialization signal PAC switches to a high logic, the initialization circuit **20** sets the voltage VOU**1** of the output node n**1** to an initialization potential. (57) FIG. **5** is an operation timing diagram of the comparators **121** shown in FIGS. **3** and **4**. In the description below, operations of the comparators **121** shown in FIGS. **3** and **4** are explained with reference to FIG. **5**. First, the period from time t**1** to time t**3** is a signal reset period. During this period, the DAC **104** outputs a reference signal of a predetermined voltage level. Further, as shown in FIG. **2**, during the signal reset period, the reset transistor in the pixel **150** is turned off after being turned on, and the FD **153** is fixed to a reset potential.
- (58) The AZP signal switches to the low potential within the period from time t1 to time t2. As a result, the sixth transistor Q6 is turned on, and the gate of the second transistor Q2 has the same potential as the output node n1 of the comparator 121. The operating point of the differential circuit 11 is set within the period from time t1 to time t2. More specifically, the bias signals BIAS_P1 and BIAS_P2 of the fourth transistor Q4 and the fifth transistor Q5 are adjusted so that the output node n1 of the comparator 121 is set at a predetermined voltage level. In this manner, negative feedback control is performed. At this stage, the bias signals BIAS_P1 and BIAS_P2 are adjusted so that the fourth transistor Q4 and the fifth transistor Q5 operate in the saturation region. As a result, the operating point of the differential circuit 11 is set. The voltage levels of the bias signals BIAS_P1 and BIAS_P2 corresponding to the set operating point are held in a capacitance (not illustrated). After time t2, the comparator 121 performs an operation of comparing the photoelectric conversion signal with the reference signal. However, while the comparator 121 is performing the comparison operation, the bias signals BIAS_P1 and BIAS_P2 are held at the voltage levels set within the period from time t1 to time t2.
- (59) When the AZP signal switches to the high level at time t**2**, the sixth transistor Q**6** is turned off. Accordingly, after time t**2**, the gate voltage of the second transistor Q**2** turns into a voltage that changes with the voltage level of the reference signal.
- (60) At time t3, the initialization signal PAC switches to a high logic, and the voltage VOU1 of the output node n1 drops to the initialization potential. Further, the DAC 104 raises the reference signal to the initial voltage level, and maintains the voltage level until time t4. As a result, the current flowing in the second transistor Q2 becomes larger than the current flowing in the first transistor Q1 in the differential circuit 11, and the voltage of the output node n1 of the comparator 121 drops. (61) The DAC 104 lowers the voltage level of the reference signal continuously or stepwise during the period from time t4 to time t6. Between time t4 and time t6, the pixel 150 has not yet performed photoelectric conversion, and the FD 153 maintains the reset potential. During the period from time

- t4 to time t5, the voltage level of the reference signal is higher than the reset potential of the FD 153. Accordingly, the current flowing in the second transistor Q2 is larger than the current flowing in the first transistor Q1 in the differential circuit 11, and the output node n1 of the comparator 121 maintains the low potential. As the voltage level of the reference signal crosses the reset potential at time t5, the current flowing in the first transistor Q1 in the differential circuit 11 is larger than the current flowing in the second transistor Q2 after time t5. As a result, the output node n1 of the comparator 121 transitions from the low potential to the high potential.
- (62) The counter **122** counts the duration from time t**4** at which the voltage level of the reference signal starts dropping till time t**5** at which the reference signal and the potential of the FD **153** cross, and the count value of the counter **122** is held by the latch **123**. The count value held by the latch **123** is a P-phase count value.
- (63) After that, during the period from time t6 to time t7, when the transfer transistor 152 shown in FIG. 2 is turned on by the electric charge photoelectrically converted by the photodiode 151, the FD 153 is lowered to the potential corresponding to the quantity of incident light. After raising the reference signal to the initial voltage level during the period from time t8 to time t9, the DAC 104 lowers the voltage level of the reference signal continuously or stepwise during the period from time t9 to time t10. While the voltage level of the reference signal is higher than the voltage level of the FD 153 (from time t9 to time t10), the current does not flow in the first transistor Q1 in the differential circuit 11 but flows in the second transistor Q2. After the voltage level of the reference signal crosses the voltage level of the FD 153 at time t10, the current flows in the first transistor Q1 in the differential circuit 11 but does not flow in the second transistor Q2. As a result, the output node n1 of the comparator 121 has the low potential during the period from time t8 to time t10, and the high potential during the period from time t10 to time t11.
- (64) The counter **122** counts the duration from time **t9** at which the voltage level of the reference signal starts dropping till time **t10** at which the reference signal and the potential of the FD **153** cross, and the count value of the counter **122** is held by the latch **123**. The count value held by the latch **123** is a D-phase count value.
- (65) The latch **123** performs CDS by calculating a difference between the P-phase count value and the D-phase count value, and generates an AD conversion signal.
- (66) FIG. **6** is a circuit diagram of a comparator **121***z* according to a comparative example. The comparator **121***z* in FIG. **6** includes a differential amplifier **16** and a current source **17**.
- (67) The differential amplifier **16** includes transistors Q**11** to Q**17**, and capacitors C**11** and C**12**. The transistors Q**11** to Q**13** are N-type MOS transistors, and the transistors Q**14** to Q**17** are P-type MOS transistors. The transistors Q**11** and Q**12** constitute a differential circuit. The transistor Q**13** is a current source connected to each source of the transistors Q**11** and Q**12**. The transistors Q**14** and Q**15** constitute a current mirror circuit, and are connected to the drains of the transistors Q**11** and Q**12**. The transistor Q**16** switches whether or not to short-circuit the gate and the drain of the transistor Q**11**. The transistor Q**17** switches whether or not to short-circuit the gate and the drain of the transistor Q**12**. The gate of the transistor Q**11** is connected to the output node of the pixel **150** and the input node of a current source **18** via the capacitor C**11**. The reference signal RAMP is input to the gate of the transistor Q**12** via the capacitor C**12**.
- (68) The current source **17** includes N-type MOS transistors Q**21** to Q**23**, a capacitor C**13**, and a constant current source **18**. The current source **17** is connected to the select transistor **155** in the pixel **150**, and forms a source follower circuit.
- (69) The comparator **121**z in FIG. **6** has a more complicated circuit configuration than that of the comparator **121** shown in FIG. **3**. In particular, the comparator **121**z in FIG. **6** includes the transistor **Q11** separately from the amplification transistor **154** and the select transistor **155** in the pixel **150**, and outputs a signal corresponding to a difference between the current flowing in the transistor **Q11** and the current flowing in the transistor **Q12** to which the reference signal is input at the gate. The comparator **121**z in FIG. **6** also includes the current source **17** connected to the output

- node of the pixel **150**. The amplification transistor **154** and the select transistor **155** in the pixel **150** in FIG. **3** are a source follower circuit, and it takes time to stabilize the potential of the output node of the pixel **150**. Therefore, in the comparator **121**z in FIG. **6**, a comparison operation needs to be performed after the potential of the output node of the pixel **150** is stabilized, and a high-speed operation is difficult. Also, the comparator **121**z in FIG. **6** has a more complicated circuit configuration than that of the comparator **121** in FIG. **3**. Therefore, the circuit area cannot be reduced, and power consumption increases. Further, in the comparator **121**z in FIG. **6**, the transistors **Q14** and **Q15** connected to the power-supply voltage node are P-type MOS transistors, and therefore, the dynamic range is narrow.
- (70) As described above, the comparator **121** in FIG. **3** can operate at a higher speed, can be made smaller in size, and can realize lower power consumption, compared with the comparator **121**z in FIG. **6**. Various modifications can be made to the circuit configuration of the comparator **121** shown in FIG. **3**.
- (71) (First Modification of the Comparator **121**)
- (72) FIG. **7** is a circuit diagram of a first modification of the comparator **121** shown in FIG. **3**. A comparator **121***a* in FIG. **7** includes an output amplifier **21**, in addition to the circuit configuration of the comparator **121** shown in FIG. **3**. The output amplifier **21** includes a seventh transistor Q**7** and an eighth transistor Q**8** cascode-connected between the power-supply voltage node VDDH and the ground node, for example. A bias signal BIAS_P**3** is supplied to the gate of the seventh transistor Q**7**, and the drain of the fifth transistor Q**5** is connected to the gate of the eighth transistor Q**8**. The output amplifier **21** is a source-grounded circuit, and can increase the gain of a signal output from the drain of the fifth transistor Q**5**. As an output voltage VOUT**2** of the comparator **121***a* is input to the counter **122** that is a digital circuit (logic circuit), the signal having the gain increased by the output amplifier **21** is output, so that a signal having an input level allowable for a digital circuit (logic circuit) can be input to the counter **122**.
- (73) (Second Modification of the Comparator **121**)
- (74) In a case where an object having a white pattern on a black background or the like is imaged, a captured image including streaks that are white lines appearing in the black background portion might be obtained.
- (75) FIG. **8** is a circuit diagram of a second modification of the comparator **121** shown in FIG. **3**, and shows a circuit configuration that takes measures against streaks when an object having a white pattern on a black background is imaged.
- (76) A comparator **121***b* in FIG. **8** includes a ninth transistor Q**9**, in addition to the circuit configuration shown in FIG. 2. The ninth transistor Q9 is an N-type MOS transistor, for example. The ninth transistor Q**9** is connected in parallel to the fourth transistor Q**4**, and is cascodeconnected to the second transistor Q2. That is, the ninth transistor Q9 and the second transistor Q2 are cascode-connected between the power-supply voltage node and the input node n2 of the first current source **13**. A bias signal BIAS_N**3** is supplied to the gate of the ninth transistor Q**9**. (77) In a case where a pixel **150** of a high luminance is photoelectrically converted, when D-phase photoelectric conversion is started after signal resetting, the potential of the FD **153** greatly drops, and the current flowing in the first transistor Q**1** of the differential circuit **11** in the comparator **121***b* in FIG. **8** decreases. The differential circuit **11** operates so that the current flowing in the first current source **13** is always constant. Therefore, the current flowing in the second transistor **Q2** is increased by the amount equivalent to the decrease in the current flowing in the first transistor Q1. However, since the voltage levels of the bias signals BIAS_P1 and BIAS_P2 to be supplied to the gate voltages of the fourth transistor Q4 and the fifth transistor Q5 are kept constant, the decrease in the current flowing in the first transistor Q1 cannot be compensated for, and streaks appear. Therefore, the ninth transistor **Q9** is newly provided so that a current can flow from the powersupply voltage node to the first current source **13** through the ninth transistor **Q9**. With this arrangement, the current flowing from the power-supply voltage node to the first current source 13

- can be made constant at all times, and streaks at the time of imaging of an object having a white pattern on a black background can be prevented from appearing.
- (78) (Third Modification of the Comparator **121**)
- (79) FIG. **9** is a circuit diagram of a third modification of the comparator **121** shown in FIG. **3**, and shows a circuit configuration that takes measures against streaks when an object having a black pattern on a white background is imaged.
- (80) A comparator **121***c* in FIG. **9** includes a tenth transistor Q**10**, in addition to the circuit configuration shown in FIG. **2**. The tenth transistor Q**10** is connected in parallel to the second transistor Q**2**. The tenth transistor Q**10** is an N-type MOS transistor, for example. The drain of the tenth transistor Q**10** is connected to the connection node n**3** between the fourth transistor Q**4** and the fifth transistor Q**5**. The source of the tenth transistor Q**10** is connected to the input node n**2** of the first current source **13**. The gate of the tenth transistor Q**10** is connected to the output node (or the drain of the fifth transistor Q**5**) n**1** of the comparator **121***c*.
- (81) In a case where the potential of the FD **153** is high at a time when the operation of acquiring a P-phase count value is switched to an operation of acquiring a D-phase count value, a large current flows on the side of the first transistor Q**1**. The voltage level of the reference signal drops with time. When the voltage level of the reference signal becomes lower than the potential of the FD **153**, almost no current flows in the second transistor Q**2**, and most of the current flows in the first transistor Q**1**. In this case, the voltage level of the power-supply voltage node on the side of the pixel **150** might cause a voltage drop due to IR (hereinafter referred to as the IR drop).
- (82) As the comparator **121***c* in FIG. **9** includes the tenth transistor Q**10** connected in parallel to the second transistor Q**2**, the decrease in the current flowing in the second transistor Q**2** can be compensated for by the tenth transistor Q**10**, and thus, the current flowing in the first transistor Q**1** can be reduced. Accordingly, the IR drop at the power-supply voltage node on the side of the pixel **150** can be prevented, and streaks at a time of imaging of an object having a black pattern on a white background can be prevented from appearing.
- (83) (Fourth Modification of the Comparator **121**)
- (84) Although the ADC according to this embodiment is provided basically for the respective pixel columns in the column direction, it is possible to adopt a modification in which one ADC is provided for each one pixel column in a plurality of pixel columns, a modification in which a plurality of pixels **150** adjacent in the row direction are added up before AD conversion, and the like.
- (85) FIG. **10** is a circuit diagram of a fourth modification of the comparator **121** shown in FIG. **3**. A comparator **121***d* in FIG. **10** compares at least one photoelectric conversion signal of a plurality of pixels **150** arranged in the row direction with a reference signal. The comparator **121***d* in FIG. **10** includes a selector **22**. The selector **22** is connected between the source of the third transistor **Q3** (the select transistor **155**) in the differential circuit **11** and the input node of the first current source 13. The selector 22 includes, for each pixel 150, a plurality of switches SW0 and SW1 for switching whether or not to connect the source of the third transistor Q3 in the corresponding pixel **150** to the input node of the first current source **13**. With this arrangement, while the photoelectric conversion signal of any one pixel **150** among the plurality of pixels **150** can be compared with the reference signal, the signal obtained by adding the photoelectric conversion signals of any two or more pixels **150** among the plurality of pixels **150** can also be compared with the reference signal. (86) In FIG. **10**, only one pixel **150** is shown in the column direction, but a plurality of pixels **150** may be disposed in the column direction. As the selector **22** is provided as shown in FIG. **10**, a smaller number of comparators **121***d* than the number of pixel columns in the column direction are required to be provided, and the circuit area of the imaging device **100** can be reduced. (87) FIG. **11** is a circuit diagram of an imaging device **100** including the comparators **121***d* shown in FIG. **10**. The imaging device **100** in FIG. **11** includes a smaller number of comparators **121***d* than

the number of pixel columns in the column direction. In the pixel unit **101**, a plurality of pixel

- columns extending in the column direction is disposed in the row direction. Each comparator **121***d* includes a selector (multiplexer) **22**, and each selector **22** can select any one, or two or more pixel columns among the plurality of pixel columns arranged in the row direction. The photoelectric conversion signal in the pixel column selected by each selector **22** is compared with the reference signal in the corresponding comparator **121***d*.
- (88) With the imaging device **100** in FIG. **11**, one or a plurality of pixel columns can be selected by each selector **22**, and the types of the pixel columns to be selected by the selectors **22** can be set as appropriate for the respective selectors **22**. With this arrangement, the target to be compared with the reference signal by the respective comparators **121***d* can also vary with each comparator **121***d*. (89) (Stacked Chip)
- (90) Each component in the imaging device **100** according to this embodiment can be disposed separately on a plurality of substrates, and these substrates may be stacked. FIG. **12**A is a layout diagram of a first substrate **31**, and FIG. **12**B is a layout diagram of a second substrate **32**. The first substrate **31** and the second substrate **32** are stacked to transmit and receive various kinds of signals with Cu—Cu joints, vias, bumps, conductive pads, or the like.
- (91) The first substrate **31** in FIG. **12**A is disposed on the light incident side. In the first substrate **31**, the pixel unit **101** and a plurality of joining portions **33** are disposed. In the joining portions **33**, Cu—Cu joints, vias, bumps, or the like for transmitting and receiving various kinds of signals between the first substrate **31** and the second substrate **32** are disposed. The joining portions **33** are disposed around the pixel unit **101**.
- (92) In the second substrate **32** in FIG. **12**B, the timing control circuit **102**, the vertical scanning circuit **103**, the DAC **104**, the ADCs **105**, the horizontal transfer scanning circuit **106**, the amplifier circuit **107**, and the signal processing circuit **108** are disposed. The ADCs **105** include the comparators **121**, the counters **122**, and the latches **123**. Also, an interface unit (I/F) **34** for outputting signals subjected to signal processing and inputting signals from the outside to each component in the second substrate **32** is disposed in the vicinity of the signal processing circuit **108**.
- (93) Further, a plurality of pads **35** is arranged along the edges of the first substrate **31** and the second substrate **32**. Bonding wires for connecting to the respective components in the respective substrates are connected to these pads **35**.
- (94) The first transistor Q1 (the amplification transistor 154) and the third transistor Q3 (the select transistor 155) in the comparator 121 shown in FIG. 3 are disposed in the pixel unit 101 in the first substrate 31, and the other transistors are disposed in a dashed line portion in the second substrate 32.
- (95) Note that what components are disposed in the first substrate **31** and the second substrate **32** can be determined as appropriate, and at least one of the components other than the first transistor Q**1** and the third transistor Q**3** in the comparator **121** may be disposed in the first substrate **31**. (96) (Effects to be Achieved by this Embodiment)
- (97) As described above, in the imaging device **100** according to this embodiment, the operating point of the differential circuit **11** is set within a signal reset period before an operation of comparing a photoelectric conversion signal with a reference signal is started, and the reference signal whose voltage level varies on the basis of the operating point is supplied to the differential circuit **11**. More specifically, within the signal reset period, the gate of the second transistor **Q2** to which the reference signal is supplied at the gate and the output node n**1** of the comparator **121** are short-circuited, the voltage level of the output node is subjected to negative feedback control, and the bias signals BIAS_P**1** and BIAS_P**2** of the fourth transistor **Q4** and the fifth transistor **Q5** constituting the second current source **14** connected to the output node are adjusted and maintained. With this arrangement, when the photoelectric conversion operation is started later, the comparison operation by the comparators **121** can be performed without depending on the characteristics and the variation of the pixels **150**, and degradation in quality of the captured image can be prevented.

- (98) Further, each comparator **121** outputs a signal corresponding to a difference between the current flowing in the amplification transistor **154** (the first transistor **Q1**) in the pixel **150** and the current flowing in the second transistor **Q2** to which the reference signal is supplied at the gate. As a result, the comparison operation by the comparators **121** can be conducted at high speed, and photoelectric conversion signals can be read at high speed. In particular, in the imaging device **100** according to the present disclosure, the output of the source follower circuit in each pixel **150** is not input to the comparator **121**, and the current flowing in the amplification transistor **154** (the first transistor **Q1**) is compared directly with the current flowing in the second transistor **Q2**. Thus, the problem in that the comparison operation cannot be performed until the output voltage of the source follower circuit is stabilized does not occur, and a high-speed operation can be performed. Furthermore, a conventional pixel **150** includes a current source connected to a source follower circuit. However, this current source is also unnecessary. Accordingly, the internal configuration of the imaging device **100** can be made simpler than that of a conventional imaging device, and downsizing and lower power consumption can be realized.
- (99) <Example Applications to Mobile Structures>
- (100) The technology (the present technology) according to the present disclosure can be applied to various products. For example, the technology according to the present disclosure may be embodied as a device mounted on any type of mobile structure, such as an automobile, an electrical vehicle, a hybrid electrical vehicle, a motorcycle, a bicycle, a personal mobility device, an airplane, a drone, a vessel, or a robot.
- (101) FIG. **13** is a block diagram showing an example of a schematic configuration of a vehicle control system as an example of a mobile structure control system to which the technology according to the present disclosure can be applied.
- (102) The vehicle control system **12000** includes a plurality of electronic control units connected to each other via a communication network **12001**. In the example depicted in FIG. **13**, the vehicle control system **12000** includes a driving system control unit **12010**, a body system control unit **12020**, an outside-vehicle information detecting unit **12030**, an in-vehicle information detecting unit **12040**, and an integrated control unit **12050**. In addition, a microcomputer **12051**, a sound/image output section **12052**, and a vehicle-mounted network interface (I/F) **12053** are illustrated as a functional configuration of the integrated control unit **12050**.
- (103) The driving system control unit **12010** controls the operation of devices related to the driving system of the vehicle in accordance with various kinds of programs. For example, the driving system control unit **12010** functions as a control device for a driving force generating device for generating the driving force of the vehicle, such as an internal combustion engine, a driving motor, or the like, a driving force transmitting mechanism for transmitting the driving force to wheels, a steering mechanism for adjusting the steering angle of the vehicle, a braking device for generating the braking force of the vehicle, and the like.
- (104) The body system control unit **12020** controls the operation of various kinds of devices provided to a vehicle body in accordance with various kinds of programs. For example, the body system control unit **12020** functions as a control device for a keyless entry system, a smart key system, a power window device, or various kinds of lamps such as a headlamp, a backup lamp, a brake lamp, a turn signal, a fog lamp, or the like. In this case, radio waves transmitted from a mobile device as an alternative to a key or signals of various kinds of switches can be input to the body system control unit **12020**. The body system control unit **12020** receives these input radio waves or signals, and controls a door lock device, the power window device, the lamps, or the like of the vehicle.
- (105) The outside-vehicle information detecting unit **12030** detects information about the outside of the vehicle including the vehicle control system **12000**. For example, the outside-vehicle information detecting unit **12030** is connected with an imaging section **12031**. The outside-vehicle information detecting unit **12030** makes the imaging section **12031** image an image of the outside

- of the vehicle, and receives the imaged image. On the basis of the received image, the outside-vehicle information detecting unit **12030** may perform processing of detecting an object such as a human, a vehicle, an obstacle, a sign, a character on a road surface, or the like, or processing of detecting a distance thereto.
- (106) The imaging section **12031** is an optical sensor that receives light, and which outputs an electric signal corresponding to a received light amount of the light. The imaging section **12031** can output the electric signal as an image, or can output the electric signal as information about a measured distance. In addition, the light received by the imaging section **12031** may be visible light, or may be invisible light such as infrared rays or the like.
- (107) The in-vehicle information detecting unit **12040** detects information about the inside of the vehicle. The in-vehicle information detecting unit **12040** is, for example, connected with a driver state detecting section **12041** that detects the state of a driver. The driver state detecting section **12041**, for example, includes a camera that images the driver. On the basis of detection information input from the driver state detecting section **12041**, the in-vehicle information detecting unit **12040** may calculate a degree of fatigue of the driver or a degree of concentration of the driver, or may determine whether the driver is dozing.
- (108) The microcomputer **12051** can calculate a control target value for the driving force generating device, the steering mechanism, or the braking device on the basis of the information about the inside or outside of the vehicle which information is obtained by the outside-vehicle information detecting unit **12030** or the in-vehicle information detecting unit **12040**, and output a control command to the driving system control unit **12010**. For example, the microcomputer **12051** can perform cooperative control intended to implement functions of an advanced driver assistance system (ADAS) which functions include collision avoidance or shock mitigation for the vehicle, following driving based on a following distance, vehicle speed maintaining driving, a warning of collision of the vehicle, a warning of deviation of the vehicle from a lane, or the like.
- (109) In addition, the microcomputer **12051** can perform cooperative control intended for automated driving, which makes the vehicle to travel automatedly without depending on the operation of the driver, or the like, by controlling the driving force generating device, the steering mechanism, the braking device, or the like on the basis of the information about the outside or inside of the vehicle which information is obtained by the outside-vehicle information detecting unit **12030** or the in-vehicle information detecting unit **12040**.
- (110) The microcomputer **12051** can also output a control command to the body system control unit **12020** on the basis of information about the outside of the vehicle acquired by the outsidevehicle information detecting unit **12030**. For example, the microcomputer **12051** can perform cooperative control intended to prevent a glare by controlling the headlamp so as to change from a high beam to a low beam, for example, in accordance with the position of a preceding vehicle or an oncoming vehicle detected by the outside-vehicle information detecting unit **12030**.
- (111) The sound/image output section **12052** transmits an output signal of at least one of a sound and an image to an output device capable of visually or auditorily notifying information to an occupant of the vehicle or the outside of the vehicle. In the example of FIG. **13**, an audio speaker **12061**, a display section **12062**, and an instrument panel **12063** are illustrated as the output device. The display section **12062** may, for example, include at least one of an on-board display and a head-up display.
- (112) FIG. **14** is a diagram showing an example of the installation positions of the imaging sections **12031**. In FIG. **14**, the imaging sections **12031** include imaging sections **12101**, **12102**, **12103**, **12104**, and **12105**.
- (113) The imaging sections **12101**, **12102**, **12103**, **12104**, and **12105** are, for example, disposed at positions on a front nose, sideview mirrors, a rear bumper, and a back door of the vehicle **12100** as well as a position on an upper portion of a windshield within the interior of the vehicle. The imaging section **12101** provided to the front nose and the imaging section **12105** provided to the

upper portion of the windshield within the interior of the vehicle obtain mainly an image of the front of the vehicle **12100**. The imaging sections **12102** and **12103** provided to the sideview mirrors obtain mainly an image of the sides of the vehicle **12100**. The imaging section **12104** provided to the rear bumper or the back door obtains mainly an image of the rear of the vehicle **12100**. The imaging section **12105** provided to the upper portion of the windshield within the interior of the vehicle is used mainly to detect a preceding vehicle, a pedestrian, an obstacle, a signal, a traffic sign, a lane, or the like.

- (114) Note that, FIG. 14 shows an example of the imaging ranges of the imaging sections 12101 to 12104. An imaging range 12111 represents the imaging range of the imaging section 12101 provided to the front nose. Imaging ranges 12112 and 12113 respectively represent the imaging ranges of the imaging sections 12102 and 12103 provided to the sideview mirrors. An imaging range 12114 represents the imaging range of the imaging section 12104 provided to the rear bumper or the back door. A bird's-eye image of the vehicle 12100 as viewed from above is obtained by superimposing image data imaged by the imaging sections 12101 to 12104, for example. (115) At least one of the imaging sections 12101 to 12104 may have a function of obtaining distance information. For example, at least one of the imaging sections 12101 to 12104 may be a stereo camera formed with a plurality of imaging elements, or may be an imaging element having pixels 150 for phase difference detection.
- (116) For example, the microcomputer **12051** can determine a distance to each three-dimensional object within the imaging ranges **12111** to **12114** and a temporal change in the distance (relative speed with respect to the vehicle **12100**) on the basis of the distance information obtained from the imaging sections **12101** to **12104**, and thereby extract, as a preceding vehicle, a nearest three-dimensional object in particular that is present on a traveling path of the vehicle **12100** and which travels in substantially the same direction as the vehicle **12100** at a predetermined speed (for example, equal to or more than 0 km/hour). Further, the microcomputer **12051** can set a following distance to be maintained in front of a preceding vehicle in advance, and perform automatic brake control (including following stop control), automatic acceleration control (including following start control), or the like. It is thus possible to perform cooperative control intended for automated driving that makes the vehicle travel automatedly without depending on the operation of the driver or the like.
- (117) For example, the microcomputer **12051** can classify three-dimensional object data on three-dimensional objects into three-dimensional object data of a two-wheeled vehicle, a standard-sized vehicle, a large-sized vehicle, a pedestrian, a utility pole, and other three-dimensional objects on the basis of the distance information obtained from the imaging sections **12101** to **12104**, extract the classified three-dimensional object data, and use the extracted three-dimensional object data for automatic avoidance of an obstacle. For example, the microcomputer **12051** identifies obstacles around the vehicle **12100** as obstacles that the driver of the vehicle **12100** can recognize visually and obstacles that are difficult for the driver of the vehicle **12100** to recognize visually. Then, the microcomputer **12051** determines a collision risk indicating a risk of collision with each obstacle. In a situation in which the collision risk is equal to or higher than a set value and there is thus a possibility of collision, the microcomputer **12051** outputs a warning to the driver via the audio speaker **12061** or the display section **12062**, and performs forced deceleration or avoidance steering via the driving system control unit **12010**. The microcomputer **12051** can thereby assist in driving to avoid collision.
- (118) At least one of the imaging sections **12101** to **12104** may be an infrared camera that detects infrared rays. The microcomputer **12051** can, for example, recognize a pedestrian by determining whether or not there is a pedestrian in imaged images of the imaging sections **12101** to **12104**. Such recognition of a pedestrian is, for example, performed by a procedure of extracting characteristic points in the imaged images of the imaging sections **12101** to **12104** as infrared cameras and a procedure of determining whether or not it is the pedestrian by performing pattern

matching processing on a series of characteristic points representing the contour of the object. When the microcomputer **12051** determines that there is a pedestrian in the imaged images of the imaging sections **12101** to **12104**, and thus recognizes the pedestrian, the sound/image output section **12052** controls the display section **12062** so that a square contour line for emphasis is displayed so as to be superimposed on the recognized pedestrian. The sound/image output section **12052** may also control the display section **12062** so that an icon or the like representing the pedestrian is displayed at a desired position.

- (119) An example of the vehicle control system to which the technology according to the present disclosure can be applied has been described so far. The technology according to the present disclosure can be applied to the imaging sections **12031** in the configuration described above. As the technology according to the present disclosure is applied to the imaging sections **12031**, display with excellent display quality can be achieved, and captured images that are easier to view can be obtained. Thus, fatigue of the driver can be reduced.
- (120) Note that the present technology can also be embodied in the configurations as described below. (1) An imaging device including: a pixel that outputs a photoelectric conversion signal corresponding to an incident light quantity; and a comparator that compares the photoelectric conversion signal with a reference signal, in which the comparator includes: a differential circuit that outputs a signal corresponding to a signal difference between the photoelectric conversion signal and the reference signal; and a differential control circuit that sets an operating point of the differential circuit within a signal reset period before an operation of comparing the photoelectric conversion signal with the reference signal is started. (2) The imaging device according to (1), in which the comparator includes a first current source connected to the differential circuit, the pixel includes a first transistor that generates a current corresponding to the photoelectric conversion signal, the differential circuit includes a second transistor that generates a current corresponding to the reference signal, the differential circuit outputs a signal corresponding to a difference between a current flowing in the first transistor and a current flowing in the second transistor, and the first current source generates and applies a current obtained by adding the current flowing in the first transistor and the current flowing in the second transistor. (3) The imaging device according to (2), in which the differential circuit includes a third transistor that is cascode-connected to the first transistor, and is turned on when the pixel to be read is read, and the first current source generates and applies a current obtained by adding a current flowing in the first transistor and the third transistor, and the current flowing in the second transistor. (4) The imaging device according to (2) or (3), in which the differential control circuit includes a second current source and a third current source that are connected in series between a first reference voltage node and a second reference voltage node, the second current source includes a fourth transistor and a fifth transistor that are cascode-connected between the first reference voltage node and an input node of the third current source, and a connection node between the fourth transistor and the fifth transistor is connected to the second transistor. (5) The imaging device according to (4), in which the differential control circuit includes an output node that outputs the signal corresponding to the signal difference, from a connection node between the second current source and the third current source, and the differential control circuit performs negative feedback control on a voltage level of the output node within the signal reset period. (6) The imaging device according to (5), in which the comparator includes a sixth transistor that switches whether or not to short-circuit a gate of the second transistor and the output node, and the sixth transistor is turned on within the signal reset period, to short-circuit the gate of the second transistor and the output node. (7) The imaging device according to (6), further including a capacitor that is connected between the gate of the second transistor and an input node of the reference signal, in which the input node of the reference signal is set at a predetermined voltage level while the sixth transistor is on. (8) The imaging device according to any one of (5) to (7), in which gate voltages of the fourth transistor and the fifth transistor are adjusted, to set the voltage level of the output node at a predetermined voltage level

within the signal reset period. (9) The imaging device according to (8), in which voltage levels of the gate voltages of the fourth transistor and the fifth transistor are maintained after the operating point is set. (10) The imaging device according to (8) or (9), in which the gate voltages of the fourth transistor and the fifth transistor are set at a voltage level at which the fourth transistor and the fifth transistor operate in a saturated state. (11) The imaging device according to any one of (8) to (10), in which each of the fourth transistor and the fifth transistor is a P-type MOS transistor, and a gate of the fifth transistor is set at a lower voltage level than a voltage level of a gate of the fourth transistor. (12) The imaging device according to any one of (5) to (11), further including a seventh transistor and an eighth transistor that are cascode-connected between the first reference voltage node and the second reference voltage node, in which a predetermined bias signal is supplied to a gate of the seventh transistor, and the output node is connected to a gate of the eighth transistor. (13) The imaging device according to any one of (5) to (11), further including a ninth transistor that is connected in parallel to the fourth transistor, and is cascode-connected to the second transistor. (14) The imaging device according to (13), in which, when a gate voltage of the first transistor drops, a gate voltage of the ninth transistor is adjusted, to apply the same current as a current flowing before the drop in the gate voltage of the first transistor to the first current source. (15) The imaging device according to any one of (5) to (14), further including a tenth transistor that is connected in parallel to the second transistor, in which the output node is connected to a gate of the tenth transistor. (16) The imaging device according to any one of (2) to (15), in which the differential circuit compares a sum of currents flowing in a plurality of the first transistors provided in a plurality of the pixels with the current flowing in the second transistor, and outputs the signal corresponding to the signal difference. (17) The imaging device according to any one of (2) to (15), further including a selector that selects at least one first transistor of a plurality of the first transistors provided in a plurality of the pixels, in which the differential circuit compares a sum of currents flowing in the at least one first transistor selected by the selector with the current flowing in the second transistor, and outputs the signal according to the signal difference. (18) The imaging device according to (1), further including: a first substrate in which a plurality of the pixels is disposed; and a second substrate that is stacked on the first substrate, the comparator being disposed in the second substrate. (19) An imaging device including: a pixel including a photoelectric conversion element and an amplification transistor; a differential circuit that is formed with the amplification transistor, a first transistor that receives a reference signal, and a first current source; a second current source and a third current source that are connected in series between a first reference voltage node and a second reference voltage node; and a second transistor disposed between the second current source and the third current source, in which a node between the second current source and the second transistor is connected to the first transistor. (20) An electronic apparatus including: a solid-state imaging device that outputs an imaging pixel signal subjected to photoelectric conversion in a plurality of pixels; and a signal processing device that performs signal processing on the basis of the imaging pixel signal, in which the solid-state imaging device includes a comparator that compares a photoelectric conversion signal with a reference signal, and the comparator includes: a differential circuit that outputs a signal corresponding to a signal difference between the photoelectric conversion signal and the reference signal; and a differential control circuit that sets an operating point of the differential circuit within a signal reset period before an operation of comparing the photoelectric conversion signal with the reference signal is started.

(121) The modes of the present disclosure are not limited to the respective embodiments described above, and include various modifications that could be conceived of by those skilled in the art. Further, the effects of the present disclosure are not limited to the effects described above. That is, various additions, modifications, and partial deletions are possible without departing from the conceptual idea and spirit of the present disclosure derived from the matters defined in the claims and equivalents thereof.

REFERENCE SIGNS LIST

(122) **11** Differential circuit **12** Differential control circuit **13** First current source **14** Second current source **15** Third current source **16** Differential amplifier **17** Current source **18** Current source **18** Constant current source **21** Output amplifier **22** Selector (multiplexer) **31** First substrate **32** Second substrate **33** joining portion **34** Interface unit (I/F) **35** Pad **100** Imaging device Pixel unit **102** Timing control circuit **103** Vertical scanning circuit **105** ADC group **105** Analog-digital converter (group) **106** Horizontal transfer scanning circuit **107** Amplifier circuit **108** Signal processing circuit **109** Pixel drive line **110** Vertical signal line **111** Horizontal transfer line **121** Comparator **121-1** Comparator 121a Comparator 121b Comparator 121c Comparator 121d Comparator 121-n Comparator **121**z Comparator **122** Counter **122-1** Counter **122-**n Counter **123** Latch **123-1** Latch **123**-*n* Latch **150** Pixel **151** Photodiode **152** Transfer transistor **154** Amplification transistor **155** Select transistor (third transistor Q3) 155 Select transistor 156 Reset transistor 157 Constant current source **12000** Vehicle control system **12001** Communication network **12010** Driving system control unit **12020** Body system control unit **12030** Outside-vehicle information detecting unit **12030** Body system control unit 12031 Imaging section 12040 In-vehicle information detecting unit 12041 Driver state detecting section **12050** Integrated control unit **12051** Microcomputer **12052** Sound/image output section **12061** Audio speaker **12062** Display section **12063** Instrument panel **12100** Vehicle **12101** Imaging section

Claims

- 1. An imaging device comprising: a pixel that outputs a photoelectric conversion signal corresponding to an incident light quantity; and a comparator that compares the photoelectric conversion signal with a reference signal, wherein the comparator includes: a differential circuit that outputs a signal corresponding to a signal difference between the photoelectric conversion signal and the reference signal; and a differential control circuit that sets an operating point of the differential circuit within a signal reset period before an operation of comparing the photoelectric conversion signal with the reference signal is started.
- 2. The imaging device according to claim 1, wherein the comparator includes a first current source connected to the differential circuit, the pixel includes a first transistor that generates a current corresponding to the photoelectric conversion signal, the differential circuit includes a second transistor that generates a current corresponding to the reference signal, the differential circuit outputs a signal corresponding to a difference between a current flowing in the first transistor and a current flowing in the second transistor, and the first current source generates and applies a current obtained by adding the current flowing in the first transistor and the current flowing in the second transistor.
- 3. The imaging device according to claim 2, wherein the differential circuit includes a third transistor that is cascode-connected to the first transistor, and is turned on when the pixel to be read is read, and the first current source generates and applies a current obtained by adding a current flowing in the first transistor and the third transistor, and the current flowing in the second transistor.
- 4. The imaging device according to claim 2, wherein the differential control circuit includes a second current source and a third current source that are connected in series between a first reference voltage node and a second reference voltage node, the second current source includes a fourth transistor and a fifth transistor that are cascode-connected between the first reference voltage node and an input node of the third current source, and a connection node between the fourth transistor and the fifth transistor is connected to the second transistor.
- 5. The imaging device according to claim 4, wherein the differential control circuit includes an output node that outputs the signal corresponding to the signal difference, from a connection node between the second current source and the third current source, and the differential control circuit

performs negative feedback control on a voltage level of the output node within the signal reset period.

- 6. The imaging device according to claim 5, wherein the comparator includes a sixth transistor that switches whether or not to short-circuit a gate of the second transistor and the output node, and the sixth transistor is turned on within the signal reset period, to short-circuit the gate of the second transistor and the output node.
- 7. The imaging device according to claim 6, further comprising a capacitor that is connected between the gate of the second transistor and an input node of the reference signal, wherein the input node of the reference signal is set at a predetermined voltage level while the sixth transistor is on.
- 8. The imaging device according to claim 5, wherein gate voltages of the fourth transistor and the fifth transistor are adjusted, to set the voltage level of the output node at a predetermined voltage level within the signal reset period.
- 9. The imaging device according to claim 8, wherein voltage levels of the gate voltages of the fourth transistor and the fifth transistor are maintained after the operating point is set.
- 10. The imaging device according to claim 8, wherein the gate voltages of the fourth transistor and the fifth transistor are set at a voltage level at which the fourth transistor and the fifth transistor operate in a saturated state.
- 11. The imaging device according to claim 8, wherein each of the fourth transistor and the fifth transistor is a P-type MOS transistor, and a gate of the fifth transistor is set at a lower voltage level than a voltage level of a gate of the fourth transistor.
- 12. The imaging device according to claim 5, further comprising a seventh transistor and an eighth transistor that are cascode-connected between the first reference voltage node and the second reference voltage node, wherein a predetermined bias signal is supplied to a gate of the seventh transistor, and the output node is connected to a gate of the eighth transistor.
- 13. The imaging device according to claim 5, further comprising a ninth transistor that is connected in parallel to the fourth transistor, and is cascode-connected to the second transistor.
- 14. The imaging device according to claim 13, wherein, when a gate voltage of the first transistor drops, a gate voltage of the ninth transistor is adjusted, to apply the same current as a current flowing before the drop in the gate voltage of the first transistor to the first current source.
- 15. The imaging device according to claim 5, further comprising a tenth transistor that is connected in parallel to the second transistor, wherein the output node is connected to a gate of the tenth transistor.
- 16. The imaging device according to claim 2, wherein the differential circuit compares a sum of currents flowing in a plurality of the first transistors provided in a plurality of the pixels with the current flowing in the second transistor, and outputs the signal corresponding to the signal difference.
- 17. The imaging device according to claim 2, further comprising a selector that selects at least one first transistor of a plurality of the first transistors provided in a plurality of the pixels, wherein the differential circuit compares a sum of currents flowing in the at least one first transistor selected by the selector with the current flowing in the second transistor, and outputs the signal according to the signal difference.
- 18. The imaging device according to claim 1, further comprising: a first substrate in which a plurality of the pixels is disposed; and a second substrate that is stacked on the first substrate, the comparator being disposed in the second substrate.
- 19. An imaging device comprising: a pixel including a photoelectric conversion element and an amplification transistor; a differential circuit that is formed with the amplification transistor, a first transistor that receives a reference signal, and a first current source; a second current source and a third current source that are connected in series between a first reference voltage node and a second reference voltage node; and a second transistor disposed between the second current source and the

third current source, wherein a node between the second current source and the second transistor is connected to the first transistor.

20. An electronic apparatus comprising: a solid-state imaging device that outputs an imaging pixel signal subjected to photoelectric conversion in a plurality of pixels; and a signal processing device that performs signal processing on a basis of the imaging pixel signal, wherein the solid-state imaging device includes a comparator that compares a photoelectric conversion signal with a reference signal, and the comparator includes: a differential circuit that outputs a signal corresponding to a signal difference between the photoelectric conversion signal and the reference signal; and a differential control circuit that sets an operating point of the differential circuit within a signal reset period before an operation of comparing the photoelectric conversion signal with the reference signal is started.